



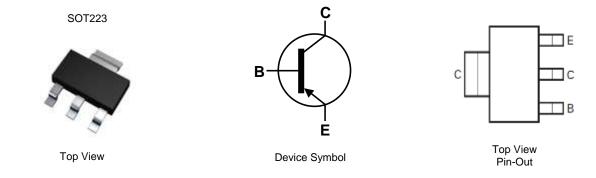
60V PNP MEDIUM POWER TRANSISTOR IN SOT223

Features

- BV_{CEO} > -60V
- I_C = -5A High Continuous Collector Current
- I_{CM} = -15A Peak Pulse Current
- Low Saturation Voltage V_{CE(SAT)} < -140mV @ -1A
- $R_{CE(SAT)} = 55m\Omega$ for a Low Equivalent On-Resistance
- hFE Specified up to -10A for a High Gain Hold-Up
- Complementary NPN Type: FZT851
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 32
- Weight: 0.112 grams (Approximate)



Ordering Information (Notes 4 & 5)

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Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FZT951TA	AEC-Q101	FZT951	7	12	1,000
FZT951TC	AEC-Q101	FZT951	13	12	4,000
FZT951QTA	Automotive	FZT951	7	12	1,000
FZT951QTC	Automotive	FZT951	13	12	4,000

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

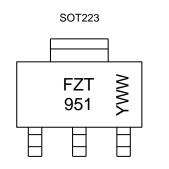
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to https://www.diodes.com/quality/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:



FZT 951 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 7 = 2017) WW or $\overline{W}W$ = Week Code (01–53)



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-100	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ι _C	-5	А
Peak Pulse Current	ICM	-15	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 6)		3.0 24	W	
Linear Derating Factor	(Note 7)	P _D	1.6 12.8	mW /°C	
Thermal Desistance, Junction to Ambient	(Note 6)	R _{0JA}	42		
Thermal Resistance, Junction to Ambient	(Note 7)	R _{0JA}	78	°C/W	
Thermal Resistance Junction to Lead	(Note 8)	R _{θJL}	8.8		
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C		

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

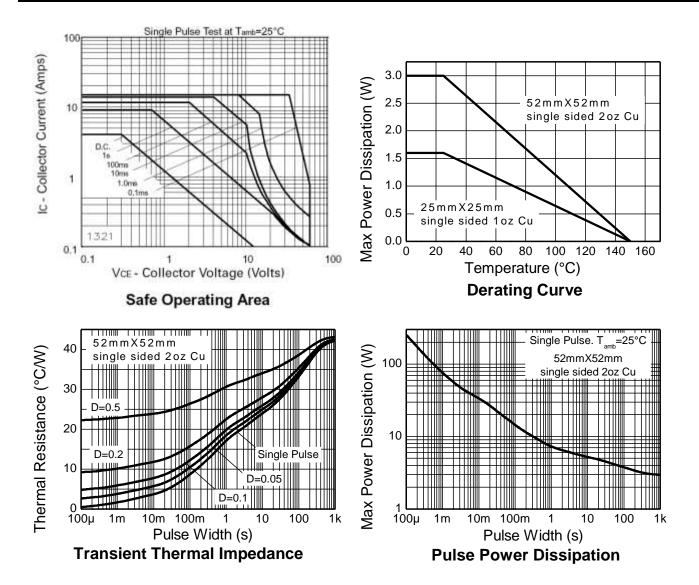
Notes: 6. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.

7. Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.

Thermal resistance from junction to solder-point (at the end of the collector lead).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information



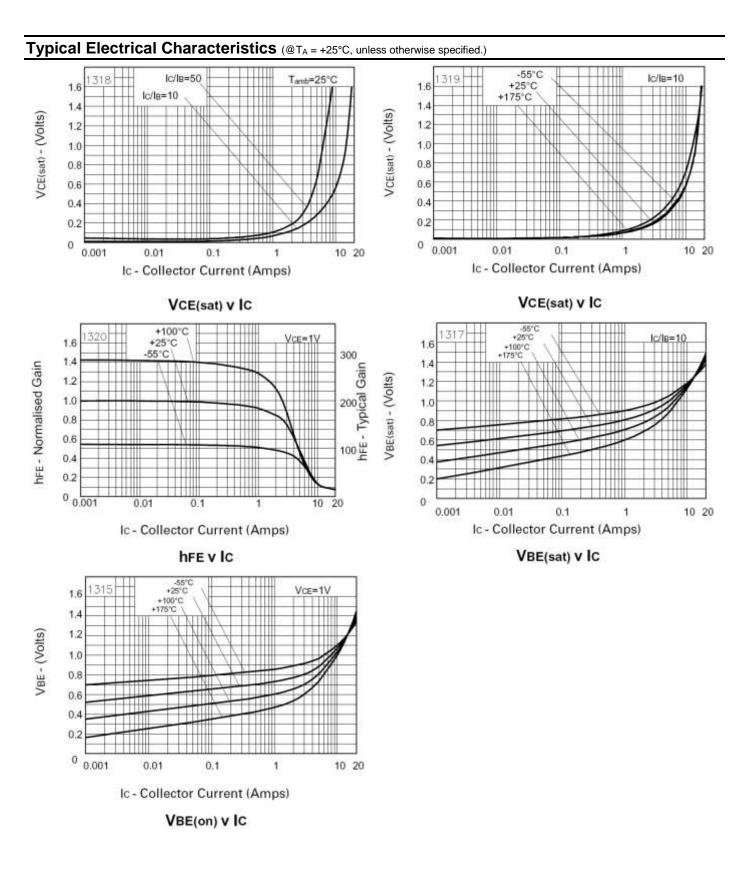


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

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Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-100	-140	—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 10)	BVCER	-100	-140		V	$I_{C} = -1\mu A, R_{B} \le 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-60	-90	—	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8	_	V	I _E = -100μA
Collector Cut-Off Current	I _{CBO}	_	<-1 —	-50 -1	nΑ μΑ	V _{CB} = -80V V _{CB} = -80V, T _A = +100°C
Collector Cut-Off Current	ICER	_	<-1 —	-50 -1	nΑ μΑ	$V_{CE} = -80V, R \le 1k\Omega$ $V_{CE} = -80V, T_A = +100^{\circ}C$
Emitter Cut-Off Current	I _{EBO}	_	<1	-10	nA	V _{EB} = -6V
		100	200	_	_	$I_{C} = -10 \text{mA}, V_{CE} = -1 \text{V}$
DC Current Transfer Statis Datis (Nate 40)		100	200	300		I _C = -2A, V _{CE} = -1V
DC Current Transfer Static Ratio (Note 10)	h _{FE}	75	90	_		I _C = -5A, V _{CE} = -1V
		10	25	_		I _C = -10A, V _{CE} = -1V
	V _{CE(SAT)}	_	-20	-50	mV	$I_{\rm C} = -100 {\rm mA}, I_{\rm B} = -10 {\rm mA}$
Collector-Emitter Saturation Voltage (Note 10)		—	-85	-140		$I_{C} = -1A, I_{B} = -100mA$
		_	-155	-210		$I_{\rm C} = -2A, I_{\rm B} = -200 {\rm mA}$
		_	-370	-460		I _C = -5A, I _B = -500mA
Base-Emitter Saturation Voltage (Note 10)	V _{BE(SAT)}	_	-1,080	-1,240	mV	I _C = -5A, I _B = -500mA
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(ON)}	_	-935	-1,070	mV	$I_{C} = -5A, V_{CE} = -1V$
Transitional Frequency (Note 10)	f _T	_	120	_	MHz	$I_{C} = -100 \text{mA}, V_{CE} = -10 \text{V}, $ f = 50MHz
Output Capacitance	Сово	_	74	_	pF	V _{CB} = -10V, f = 1MHz
Switching Time	t _{ON}		82	—	20	$V_{CC} = -10V, I_C = -2A,$
Switching Time	toff	_	350	_	ns	$-I_{B1} = I_{B2} = -200 \text{mA}$

Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



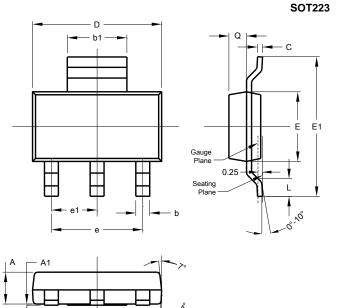


FZT951



Package Outline Dimensions

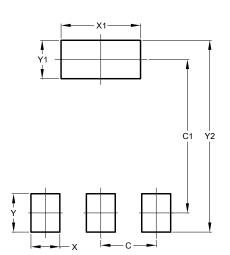
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT223				
Dim	Min	Max	Тур	
Α	1.55	1.65	1.60	
A1	0.010	0.15	0.05	
b	0.60	0.80	0.70	
b1	2.90	3.10	3.00	
С	0.20	0.30	0.25	
D	6.45	6.55	6.50	
ш	3.45	3.55	3.50	
E1	6.90	7.10	7.00	
e	-	-	4.60	
e1	-	-	2.30	
L	0.85	1.05	0.95	
Q	0.84	0.94	0.89	
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions Value (in mm) 2.30 С C1 6.40 Х 1.20 X1 3.30 Υ 1.60 Y1 1.60 Y2 8.00

 — — E E1
Gauge
Plane 0.25 Seating L

SOT223



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